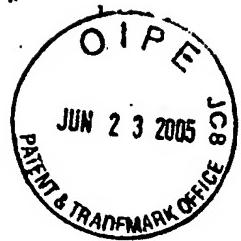


IPW



In The United States Patent and Trademark Office

Application Number 10/750588

Application Filed 31 December 2003

Applicants: Thomas J. Wells, Robert Scott Elliott

Title: Micro-Electrometer

Examiner / GAU: Vincent Q. Nguyen / 2858

Amendment A

Commissioner for Patents

Washington, District of Columbia 20231

Sir:

In response to the Office Letter mailed 10 March 2005, please amend the above application as follows:

Specification:

Page 2, last sentence, replace with the following sentence:

Leakage currents of 10 sup-10 amps and input resistances of 10 sup 11 ohms are typical for diode gate protected MOSFETs.

Page 7, last sentence of DESCRIPTION OF THE INVENTION, replace with the following sentence:

Screen resistor 33 connects to the screen grid (second and fourth grids) terminal of tube 37'.